

A Novel Compact Triple Bandpass Filter Using Loaded Microstrip Resonator with Interdigital Capacitor

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Abstract

In this paper, a compact triple-narrowband bandpass filter is designed and proposed using microstrip resonators in combination with interdigital capacitor. The proposed triple-band BPF consists of two half-wave resonators in combination with a simple anti-parallel coupled lines which realizes a triple-band BPF with a size reduction about 42% in comparison with the conventional one. To demonstrate three bands, three different coupling paths are realized between two resonators.

To improve the insertion loss of the filter, the proposed structure is combined with an interdigital capacitor. Additionally, transmission zeroes of the proposed structure guarantee the sharpness the skirts of scattering parameters of triple-band BPF. The frequency response of the filter is simulated using an EM simulation tool and then measured where a good agreement between them is reported.

Key words: Anti-parallel coupled lines, half-wave resonator, interdigital capacitor, triple-narrowband bandpass filter.

1. Introduction

Current advancements in modern wireless communication systems demonstrate the needs for smaller and low-cost microwave components. In this connection, several communication systems such as personal ones operate in multi bands which necessary narrow-band kinds of such components. Dual/triple-narrowband bandpass filters (BPF) are one of the most popular components increasingly investigated in the most recent studies. Many triple-band BPFs have been introduced by different topologies in several investigations: however, they still occupy a relatively large area on their substrates and often with complicated structures [1-10]. For instance, a triple-band BPF has been proposed in [3] using asymmetric coupled lines where it has been designed using multi-layered technology with a size about $64 \times 38 \text{ mm}^2$ on its substrate.

Moreover, a triple-band bandpass filter has recently been developed using stepped-impedance resonators (SIRs) which provide dual-band bandpass one, though its size is about 533 mm² that is still relatively large on circuit boards [4].

Furthermore, another triple-band BPF has been analyzed and introduced in [5] by an active size around 24× 19.5 mm².

Besides, several techniques based on microstrip open and closed loop resonators have been discussed on different studies [6-7]. Although, they have simple design procedure, they occupy large area on their substrate.

Here is a novel compact triple-band BPF designed, simulated and measured using the combination of half-wave resonators and anti-parallel coupled lines. The proposed BPF realizes a compact triple-band one. It is designed and simulated on a 25-mill-thickness substrate with a constant dielectric of 10.2.

2. Design procedure

As stated, this paper introduces a new kind of triple-band BPF developed using a combination of half-wave resonators and anti-parallel coupled lines. Fig.1 shows the schematic diagram of this proposed triple-band BPF where three different coupling paths are realized between two resonators to demonstrate three bands, indicated by coupling 1, 2 and 3.

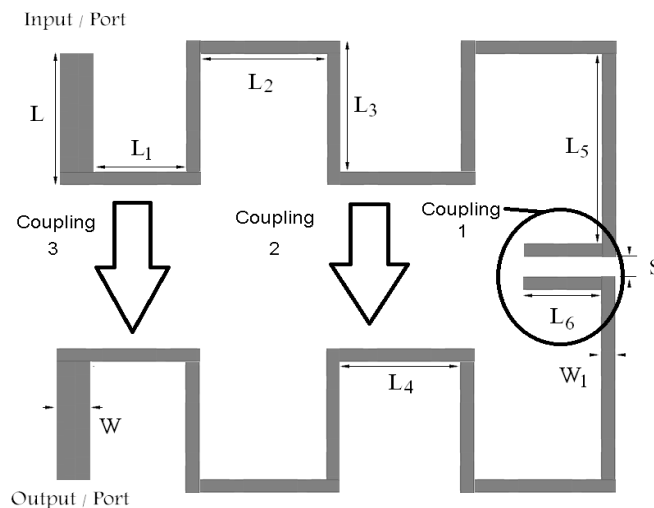


Fig.1. The structure of the conventional microstrip open-loop resonators

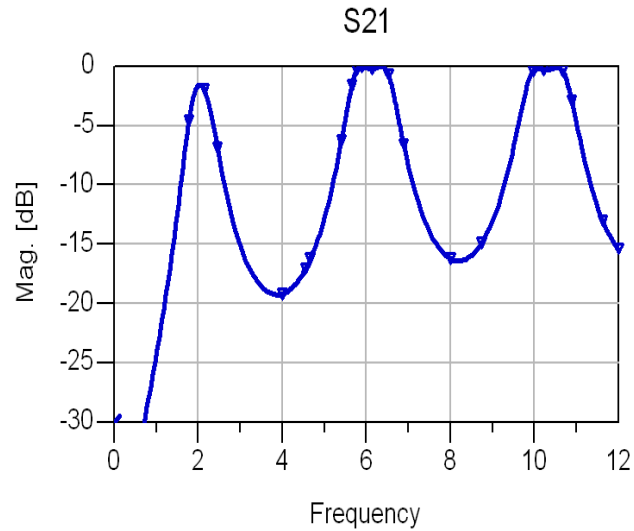
As provided in Fig.1, the proposed structure consist of two half-wave length resonator where three coupling regions are realized between two resonators to create three different resonance frequencies. As shown in Fig.1, the coupling region number 1, demonstrated by anti-parallel coupled lines realizes the funnmamental resonace frequency of the filter and two other parasitic coupling of number 2 and 3 create the second and third resonance frequencies.

The proposed layout of the triple band band-pass filter is simulated on a 31-mill-thickness substrate with a constant dielectric of 2.2 and the indicated parameters on the structure are optimized using a full-wave simulator tool (ADS) where the table 1 gives these optimized parameters.

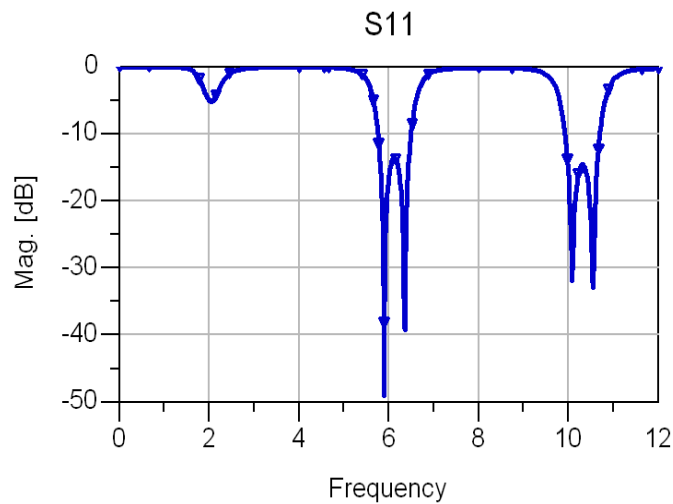
Parameter	L	L ₁	L ₂	L ₃	L ₄
Value	1.07	2	5	2.14	2
Parameter	L ₅	L ₆	S	W	W ₁
Value	5	3	0.05	0.5	0.07

Table 1 . Optimized parameters of the proposed topology shown in Fig.1

After optimization of the parameters, the performance of the proposed triple-band band-pass filter is simulated using ADS software where Fig.2 shows the frequency response of the filter in terms of the insertion and return losses, respectively.



(a)



(b)

Fig. 2. The frequency response of the proposed triple-band bandpass filter in terms of (a) insertion loss (b) return loss

Observing the performance of the proposed structure, this novel filter provides three different bands located at 2 GHz, 6.1 GHz and 10.4 GHz.

Additionally, the performance of the proposed filter is simulated in terms of current distribution where Fig.3 shows this parameter at the third resonance frequency. As observed here the maximum amount of current is distributed in three coupling regions.

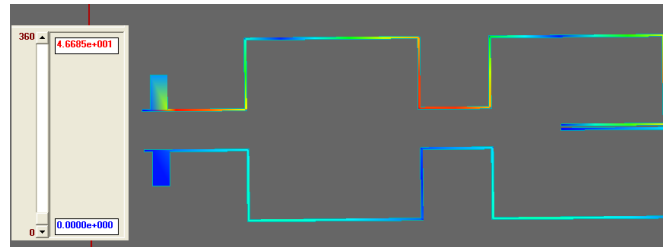


Fig.3. The current distribution of the proposed triple-band band-pass filter at the third resonance frequency

The main disadvantage of the proposed filter is the high insertion and return losses in the first band of the frequency response which is tried to improve these by upgrading the structure of the filter by incorporating of the interdigital capacitor instead of the anti-parallel coupled lines. Fig. 4 shows the schematic diagram of the improved structure including two microstrip resonators in combination with interdigital capacitor.

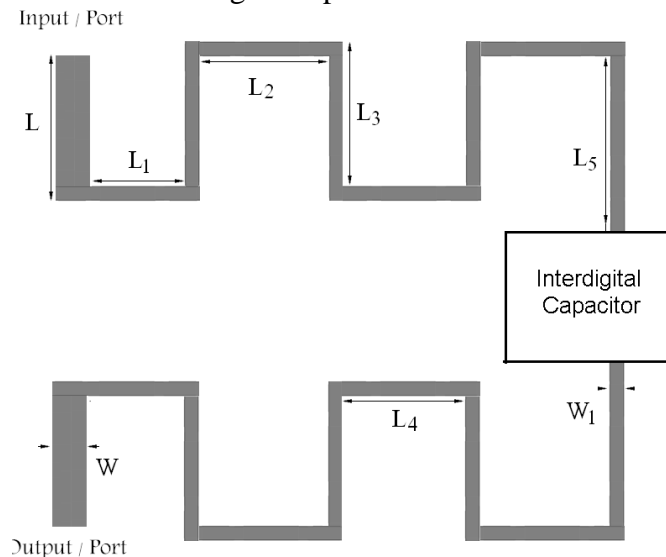


Fig.4. The layout of the proposed filter using two microstrip resonators and interdigital capacitor

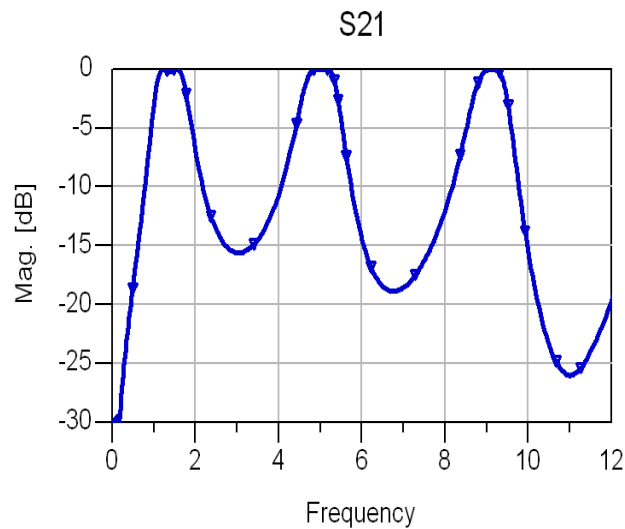
3. Simulation results

According to the given specifications in the previous sections, to improve the insertion and return loss of the proposed filter, a compact triple-band bandpass filter can be designed and simulated using a novel combination of half-wave resonators and interdigital capacitor. The proposed topology shown in Fig.1 is thus implemented by interdigital capacitor instead of the anti-parallel coupled lines and simulated using an EM simulator tool (ADS). A fine tuning process is carried out to optimize the dimensions to have a triple-band bandpass filter. Table 2 gives the optimized parameters of the interdigital capacitor.

Parameter	L	W	W_1	G	S
Value	2	0.1	0.6	0.12	0.12

Table 2 . The optimized parameters of the interdigital capacitor

Fig. 5 shows the simulated frequency response of the proposed triple-band bandpass filter in terms of the insertion and return losses, respectively



(a)

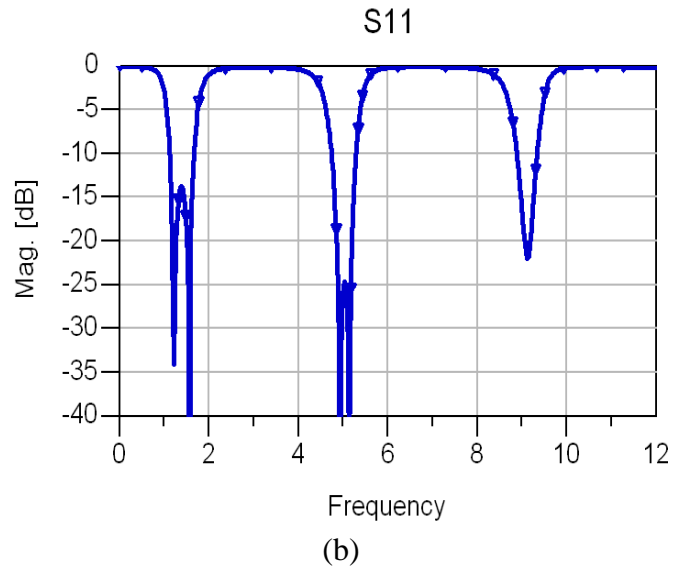
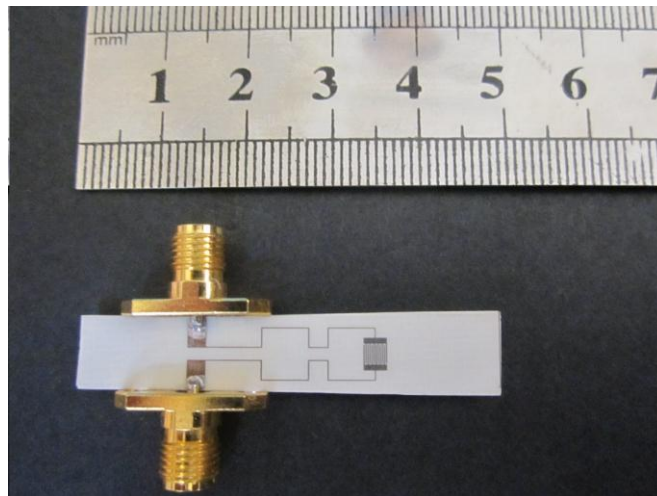
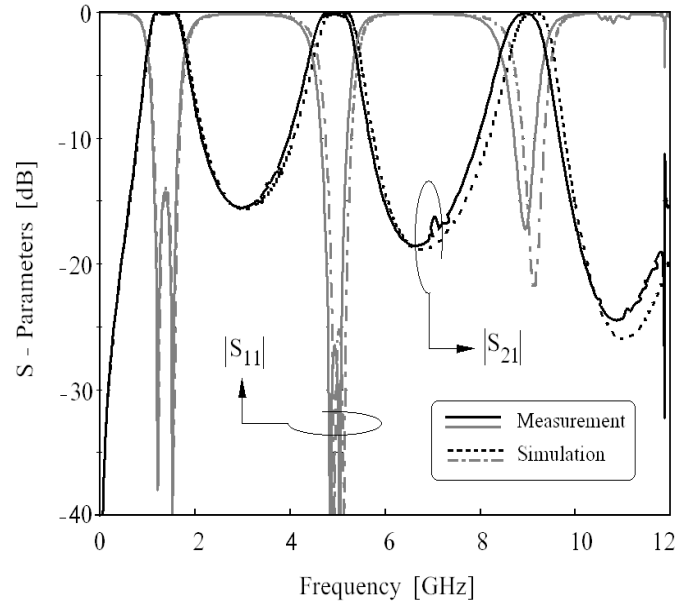


Fig. 5. The frequency response of the proposed triple-band bandpass filter in terms of (a) insertion loss (b) return loss

The triple-band BPF is then fabricated on a 25-mil-thickness RT/Duroid with dielectric constant 10.2, shown in Fig. 6 (a) and measured its performance using an Agilent 8722D network analyzer where a comparison between measured and simulated performance of this filter is presented in Fig.6 (b).



(a)



(b)

Fig.6 . (a) the digital photograph of the filter (b) its simulated and measured performance

Comparing the frequency responses of the filter using anti-parallel coupled lines – given in Fig.2- and the one with interdigital capacitor – given in Fig.4-, the use of interdigital capacitor obviously improves the insertion and return losses of the filter in the first band.

Measured central frequencies are 1765 MHz , 5030 MHz and 9025 MHz , making this compact triple-band BPF very attractive and suitable for applications in the mobile and personal communication systems (PCS's). Besides, the maximum insertion losses are reported to be 0.7 dB, 0.4 dB and 1 dB in the first, second and third bands, respectively. The return losses for these three bands are better than -14 dB, -25 dB and -21 dB, respectively.

4. Conclusions

In this paper, a miniaturized triple-narrowband bandpass filter has been designed and proposed using microstrip resonators. The proposed triple-band BPF consists of two half-wave resonators in combination with an interdigital capacitor which realizes a triple-band BPF with a size reduction about 42% in comparison with the conventional one. To realize three pass-bands, three coupling regions are demonstrated between two resonators. Additionally, transmission zeroes of the proposed structure guarantee the sharpness the skirts of scattering parameters of triple-band BPF. The frequency response of the filter has been simulated using an EM simulation tool.

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